# VS-130-160MT..KPbF Series

**Vishay Semiconductors** 

## Three Phase Bridge, 130 A to 160 A (Power Modules)



www.vishay.com

PRIMARY CHARACTERISTICS			
Ι <sub>Ο</sub>	130 A to 160 A		
V <sub>RRM</sub>	800 V to 1600 V		
Package	MTK		
Circuit configuration	Three phase bridge		

## **FEATURES**

· Package fully compatible with the industry standard INT-A-PAK power modules series



COMPLIANT

- High thermal conductivity package, electrically insulated case
- · Excellent power volume ratio
- 4000 V<sub>BMS</sub> isolating voltage
- UL E78996 approved
- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

A range of extremely compact, encapsulated three phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and heavy duty applications.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES 130MT.K	VALUES 160MT.K	UNITS	
1		130 (160)	160 (200)	A	
IO	T <sub>C</sub>	85 (62)	85 (60)	°C	
1	50 Hz 1130 1430	1430	Α		
IFSM	60 Hz	1180	1500		
l <sup>2</sup> t	50 Hz	6400	10 200	– A <sup>2</sup> s	
1-1	60 Hz	5800	9300	A <sup>2</sup> S	
l²√t		64 000	102 000	A²√s	
V <sub>RRM</sub>	Range	800 to 1600		V	
T <sub>Stg</sub>	Banga	-40 to 150			
TJ	Range	-40 to 150		- °C	

## **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = MAXIMUM mA	
VS-130MT.K VS-160MT.K	80	800	900		
	100	1000	1100		
	120	1200	1300	10	
	140	1400	1500		
	160	1600	1700		

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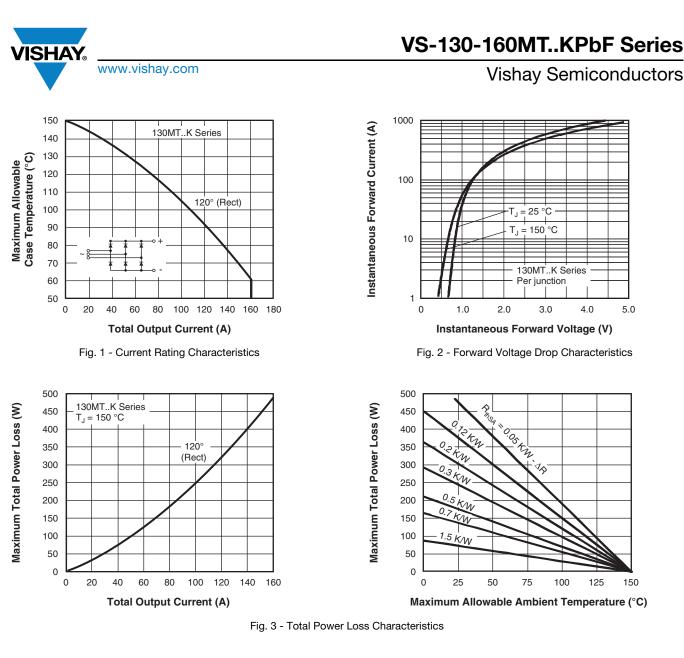


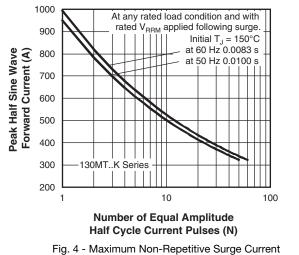
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## EODWARD CONDUCTION

FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES 130MT.K	VALUES 160MT.K	UNITS	
Maximum DC output current	1	120° rect. conduction angle		130 (160)	160 (200)	А	
at case temperature	Ι <sub>Ο</sub>			85 (62)	85 (60)	°C	
		t = 10 ms	No voltage	e	1130	1430	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		1180	1500	
forward, non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>BBM</sub>		950	1200	A
		t = 8.3 ms	reapplied	Initial	1000	1260	†
Maximum I <sup>2</sup> t for fusing		t = 10 ms	No voltage	$T_J = T_J$ maximum	6400	10 200	A <sup>2</sup> s
	l <sup>2</sup> t	t = 8.3 ms	reapplied		5800	9300	
		t = 10 ms	100 % V <sub>RRM</sub>	-	4500	7200	
		t = 8.3 ms	reapplied		4100	6600	
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied		64 000	102 000	A²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π x I <sub>T(AV)</sub> < I < π x I <sub>T(AV)</sub> ), T <sub>J</sub> maximum		0.78	0.81	V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_J$ maximum			0.99	1.04	v
Low level value of forward slope resistance	r <sub>f1</sub>	16.7 % x $\pi$ x I <sub>T(AV)</sub> < I < $\pi$ x I <sub>T(AV)</sub> ), T <sub>J</sub> maximum		4.59	3.52	- mΩ	
High level of forward slope resistance	r <sub>f2</sub>	(I > $\pi$ x I <sub>T(AV)</sub> ), T <sub>J</sub> maximum		4.17	3.13	11152	
Maximum forward voltage drop	V <sub>FM</sub>	$I_{pk}$ = 200 A, $T_J$ = 25 °C, $t_p$ = 400 $\mu s$ single junction		1.63	1.49	V	
RMS isolation voltage	V <sub>ISOL</sub>	$T_J = 25 \text{ °C}$ , all terminal shorted f = 50 Hz, t = 1 s		40	000		

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES 130MT.K	VALUES 160MT.K	UNITS
Maximum junction operating and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to 150		°C
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation per module	0.16	0.12	K/W
		DC operation per junction	0.93	0.73	
		120° rect. conduction angle per module	0.18	0.15	
		120° rect. conduction angle per junction	1.08	0.88	
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Per module Mounting surface smooth, flat and greased	0.03		
Mounting to heatsink		A mounting compound is recommended and	4 t	o 6	Nm
torque ± 10 % to terminal		the torque should be rechecked after a period of 3 hours to allow for the spread of the	3 t	o 4	
Approximate weight		compound. Lubricated threads.	17	76	g





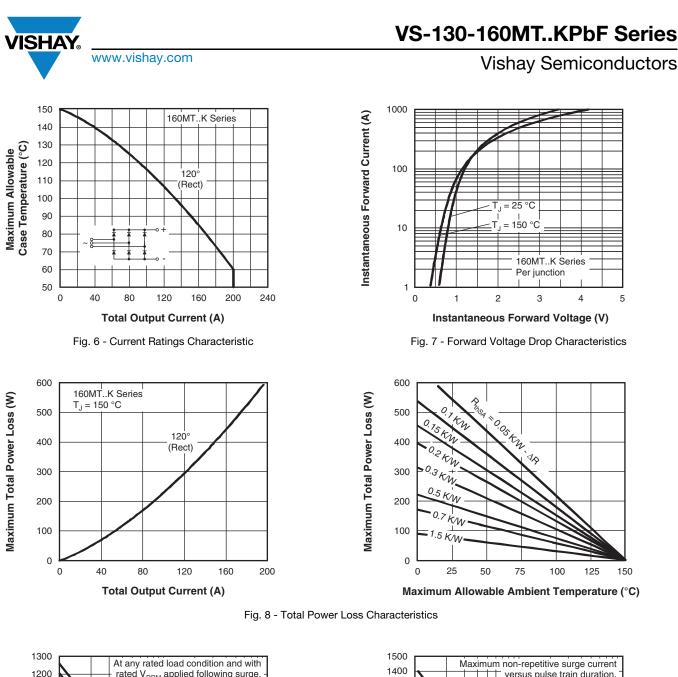
1200 Maximum non-repetitive surge current 1100 versus pulse train duration. Initial T<sub>.1</sub> = 150 °C 1000 No voltage reapplied Peak Half Sine Wave Forward Current (A) Rated V<sub>BBM</sub> reapplied 900 800 700 600 500 400 130MT..K Series 300 200 0.01 0.1 1.0 Pulse Train Duration (s)

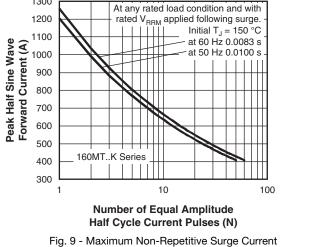
Fig. 5 - Maximum Non-Repetitive Surge Current

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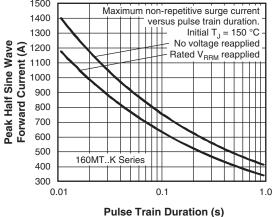


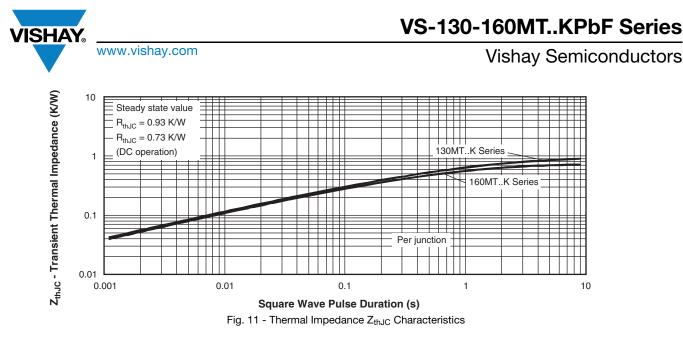
Fig. 10 - Maximum Non-Repetitive Surge Current

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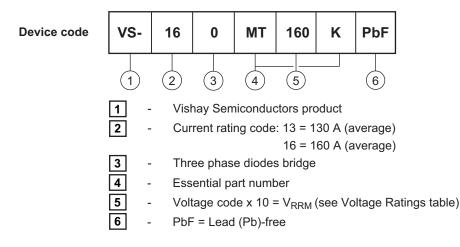
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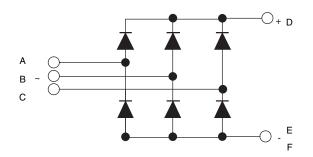
## **ORDERING INFORMATION TABLE**



#### Note

To order the optional hardware go to: <u>www.vishay.com/doc?95172</u>

## **CIRCUIT CONFIGURATION**



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95004			

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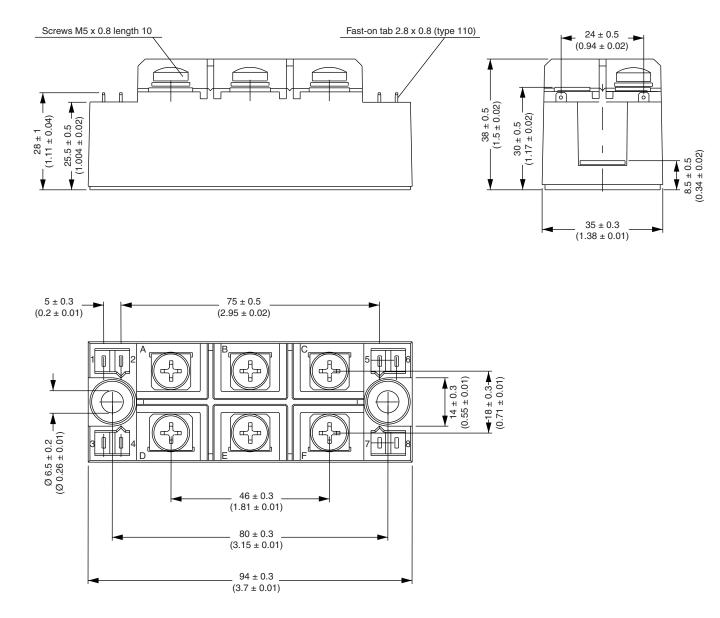


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# MTK (with and without optional barrier)

## **DIMENSIONS WITH OPTIONAL BARRIERS** in millimeters (inches)

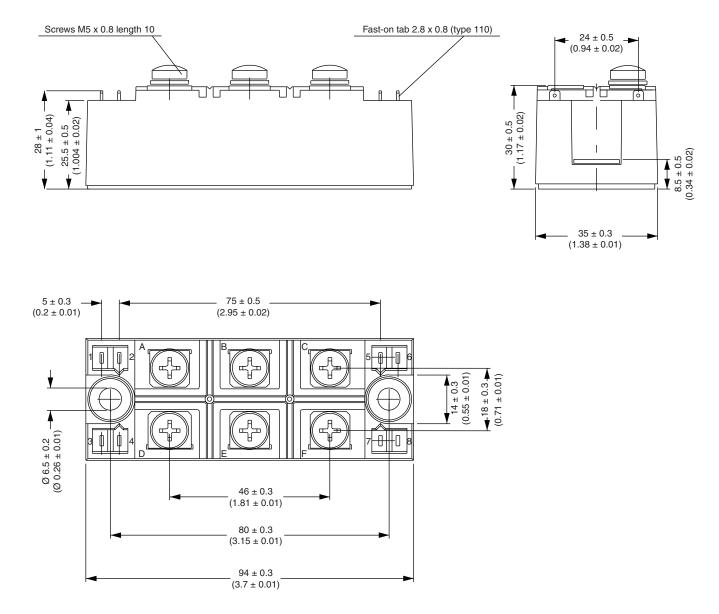
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Vishay Semiconductors MTK (with and without optional barrier)



## DIMENSIONS WITHOUT OPTIONAL BARRIERS in millimeters (inches)





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